

isc Silicon NPN Power Transistor
2SD1880
DESCRIPTION

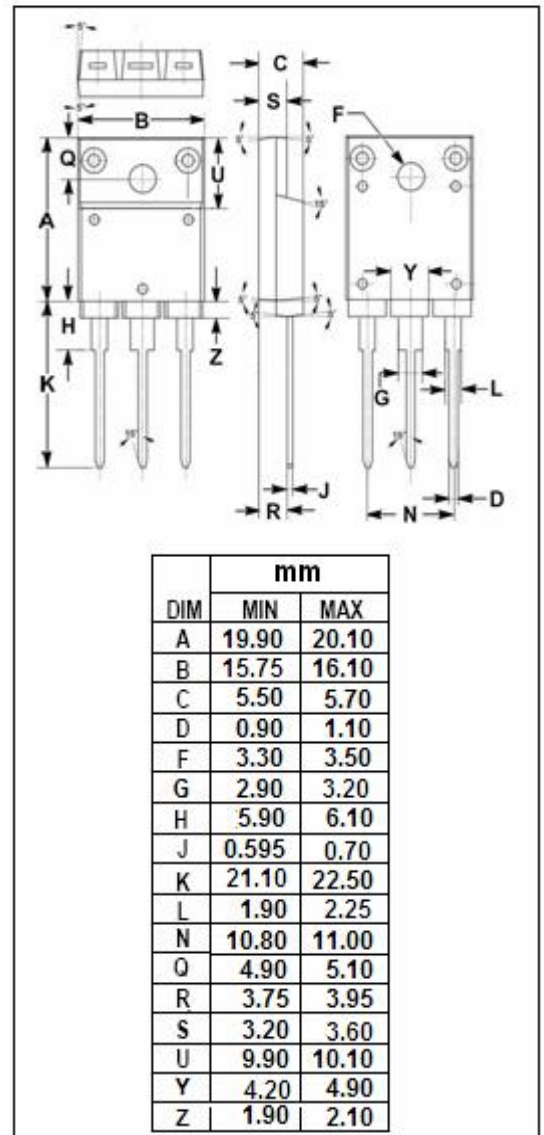
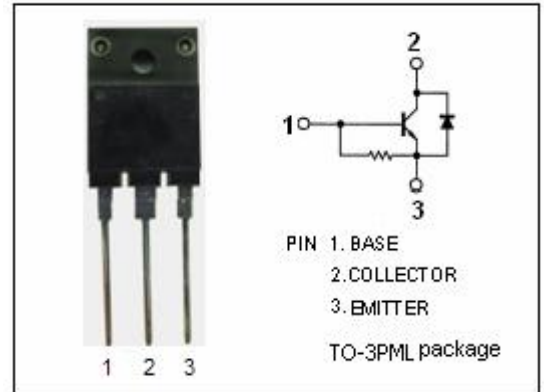
- High Breakdown Voltage-
: $V_{CBO} = 1300V$ (Min)
- High Switching Speed
- High Reliability
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Color TV horizontal deflection output
- Color display horizontal deflection output

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|---|---------|------------|
| V_{CBO} | Collector-Base Voltage | 1300 | V |
| V_{CEO} | Collector-Emitter Voltage | 800 | V |
| V_{EBO} | Emitter-Base Voltage | 6 | V |
| I_C | Collector Current- Continuous | 8 | A |
| I_{CP} | Collector Current-Pulse | 30 | A |
| P_C | Collector Power Dissipation @ $T_C = 25^\circ C$ | 70 | W |
| T_J | Junction Temperature | 150 | $^\circ C$ |
| T_{stg} | Storage Temperature Range | -55~150 | $^\circ C$ |



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ELECTRICAL CHARACTERISTICS
T_c=25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|-----------------------|--------------------------------------|---|-----|------|-----|------|
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 50mA; I _B = 0 | 800 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 6A; I _B = 1.2A | | | 5.0 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 6A; I _B = 1.2A | | | 1.5 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 800V ; I _E = 0 | | | 10 | μ A |
| I _{CES} | Collector Cutoff Current | V _{CE} = 1300V ; R _{BE} = 0 | | | 1.0 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 4V ; I _C = 0 | 40 | | 130 | mA |
| h _{FE-1} | DC Current Gain | I _C = 1A ; V _{CE} = 5V | 8 | | | |
| h _{FE-2} | DC Current Gain | I _C = 6A ; V _{CE} = 5V | 5 | | 10 | |
| V _{ECF} | C-E Diode Forward Voltage | I _F = 8A | | | 2.0 | V |
| t _f | Fall Time | I _C = 6A , I _{B1} = 1.2A ; I _{B2} = -2.4A P _W =20 μ s; Duty Cycle ≤ 1% | | | 0.3 | μ s |

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